

FEB 01 2006

BY TELEFAX 571-273-8300

DOCKET NO.: 4887

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN THE MATTER OF THE APPLICATION FOR PATENT

OF: Makoto OTSUKI et al.

ART UNIT: 2812

SERIAL NO.: 10/537,529

CONF. NO.: 4558

FILED: June 3, 2005

FOR: METHOD OF MANUFACTURING SINGLE-CRYSTAL SEMICONDUCTOR WAFERS
AND LASER MACHINING APPARATUS THEREFORMAIL STOP MISSING PARTS
COMMISSIONER FOR PATENTS
P.O. BOX 1450
ALEXANDRIA, VA 22313-1450

February 1, 2006

REQUEST FOR CORRECTION OF CORRECTED OFFICIAL FILING RECEIPT

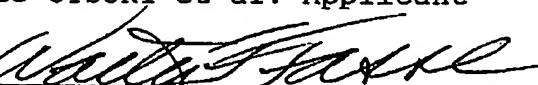
Dear Sir:

- 1) The Corrected Official Filing Receipt contains an error. Please correct the following item as shown on the enclosed marked-up copy of the Corrected Filing Receipt:
 - Title
- 2) The requested correction is supported by the inventors' Declaration and specification filed on June 3, 2005.
- 3) Please issue a corrected Filing Receipt.

Respectfully submitted,
Makoto OTSUKI et al.-Applicant

WFF:ks/4887

By


W. F. Fasse - Patent Attorney

Enclosure:

Reg. No.: 36132

Hand-corrected

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CERTIFICATE OF FAX TRANSMISSION:

I hereby certify that this correspondence with all indicated enclosures is being transmitted by telefax to 571-273-8300 on the date indicated below, and is addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Karin Smith - February 1, 2006
Name: Karin Smith - Date: February 1, 2006



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| 10/537,529 | 06/03/2005 | 2812 | 1900 | 4887/PCT | 5 | 40 | 2 |

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Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please mail to the Commissioner for Patents P.O. Box 1450 Alexandria Va 22313-1450. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

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Assignment For Published Patent Application

Sumitomo Electric Industries, Ltd., Osaka-shi, JAPAN

Power of Attorney: The patent practitioners associated with Customer Number 21553.

Domestic Priority data as claimed by applicant

This application is a 371 of PCT/JP04/08108 06/10/2004

Foreign Applications

JAPAN 2003-176746 06/20/2003

If Required, Foreign Filing License Granted: 01/25/2006

The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is US10/537,529

Projected Publication Date: Not Applicable

Non-Publication Request: No

~~See Title on page 2~~

Page 2 of 3

Early Publication Request: No~~X~~ **Title**

Method of manufacturing single-crystal semiconductor wafers and laser machining apparatus
therefor

C~~X~~ **Preliminary Class**

438

~~X~~**PROTECTING YOUR INVENTION OUTSIDE THE UNITED STATES**

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